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Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET

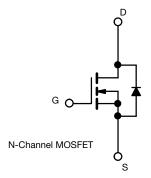


PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.036			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.040			
I _D (A)	24			
Configuration	Single			
Package	PowerPAK SO-8L			

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ABSOLUTE MAXIMUM RATINGS ($T_{\rm C}$	= 25 °C, unles	s otherwise noted)	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	60	V
Gate-source voltage		V_{GS}	± 20	V
Continuous drain current	T _C = 25 °C ^a	1	24	
Continuous drain current	T _C = 125 °C	I _D	14	
Continuous source current (diode conduction) ^a		I _S	49	Α
Pulsed drain current b		I _{DM}	96	
Single pulse avalanche current	L = 0.1 mH	l _{AS}	17	
Single pulse avalanche energy	L=0.11IIII	E _{AS}	14.4	mJ
Maximum power dissipation	T _C = 25 °C	P _D	29.4	W
Maximum power dissipation	T _C = 125 °C	r _D	9.8	VV
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C
Soldering recommendations (peak temperature) ^d			260	C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount c	R_{thJA}	42	°C/W
Junction-to-case (drain)		R_{thJC}	2.8	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static				l	l	I	ı
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = 250 μA	60	-	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μΑ
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	30	-	-	Α
		V _{GS} = 10 V	I _D = 15 A	-	0.029	0.036	
Duning and an atota unalista and a		V _{GS} = 10 V	I _D = 15 A, T _J = 125 °C	-	-	0.075	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 15 A, T _J = 175 °C	-	-	0.096	Ω
		V _{GS} = 4.5 V	I _D = 15 A	-	0.032	0.040	
Forward transconductance b	9 _{fs}	V_{DS}	= 15 V, I _D = 10 A	-	30	-	S
Dynamic ^b							•
Input capacitance	C _{iss}			-	705	987	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	85	119	pF
Reverse transfer capacitance	C _{rss}			-	21	30	
Total gate charge ^c	Qg			-	13	20	
Gate-source charge c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 30 \text{ V}, I_{D} = 10 \text{ A}$	-	3	-	nC
Gate-drain charge c	Q _{gd}			-	2	-	
Gate resistance	R _g		f = 1 MHz	2.1	4.2	6.3	Ω
Turn-on delay time c	t _{d(on)}			-	7	11	
Rise time ^c	t _r	V _{DD} =	= 30 V, $R_L = 3.0 \Omega$	-	3	6	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 10 \text{ A},$	$V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	19	29	ns
Fall time ^c	t _f			-	1	2	
Source-Drain Diode Ratings and Chara	acteristics ^b						
Pulsed current ^a	I _{SM}			-	-	96	Α
Forward voltage	V _{SD}	I _F =	15 A, V _{GS} = 0 V	-	-	1.1	V
Body diode reverse recovery time	t _{rr}			-	19	38	ns
Body diode reverse recovery charge	Q _{rr}]	۸ ما:/مله ۱۰۰ ۸ /··-	-	17	34	nC
Reverse recovery fall time	t _a	I _F = 10	A, di/dt = 100 A/μs	-	14	-	
Reverse recovery rise time	t _b	7		-	5	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	1.9	-	Α

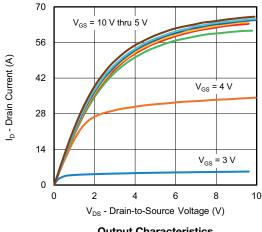
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

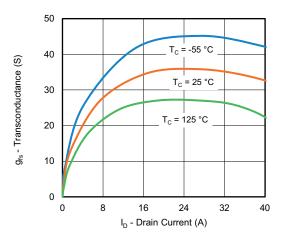
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



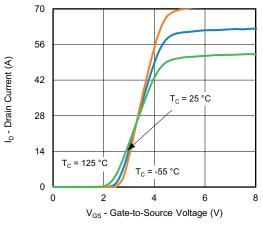
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



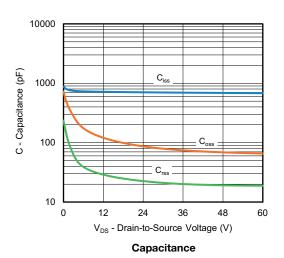
Output Characteristics

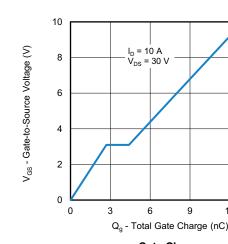


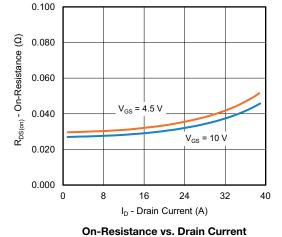
Transconductance



Transfer Characteristics







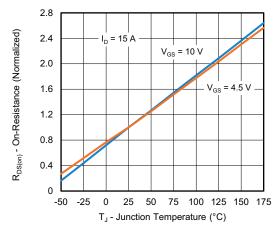
Gate Charge

15

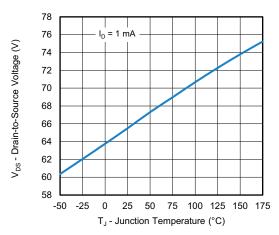
12



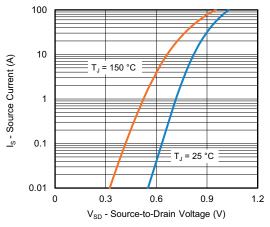
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



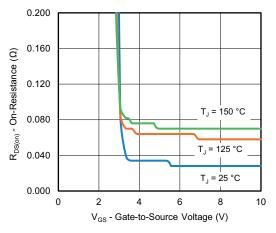
On-Resistance vs. Junction Temperature



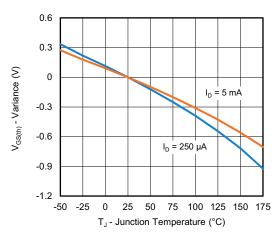
Drain Source Breakdown vs. Junction Temperature



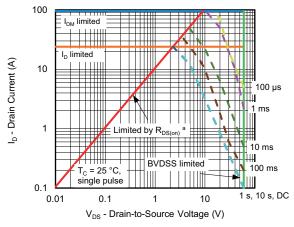
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to Source Voltage



Threshold Voltage



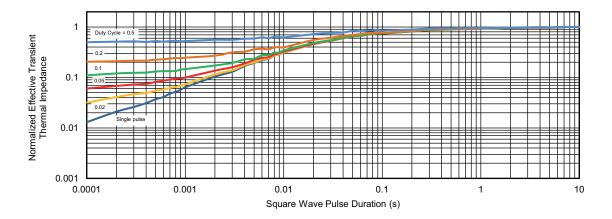
Safe Operating Area

Note

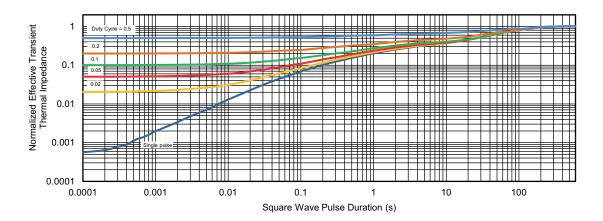
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

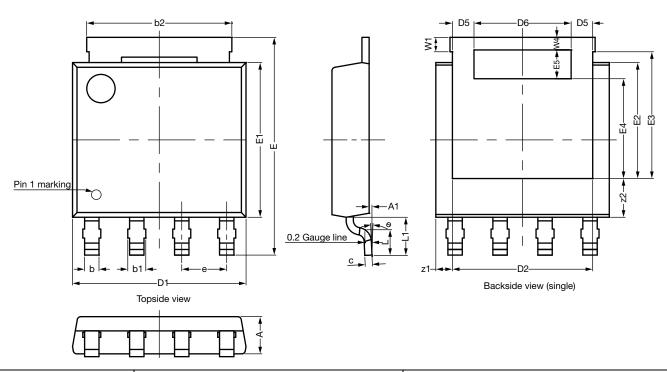


Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63078.



PowerPAK® SO-8L (PPKSO8LWLA) Case Outline 3



DIM.		MILLIMETERS		INCHES			
DIIVI.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	

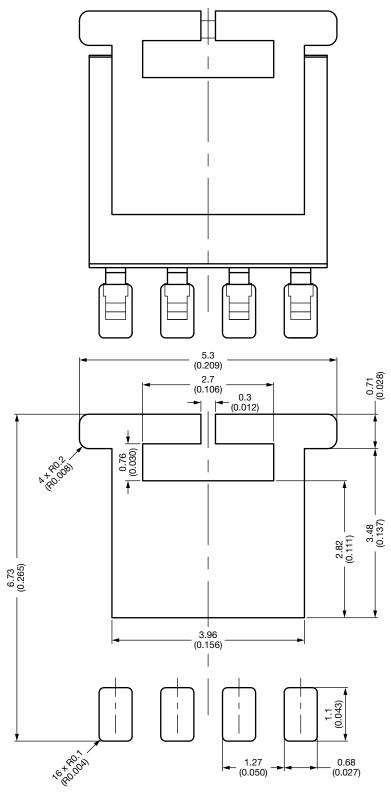
Note

• Millimeter will govern

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Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)



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